EAST - [10721440 wsp:1]

s61 and mitride and thickness

Unizergenia (m. v.)

C[# 되기 | 기술 위 기속] \$\$50: (3) 543 and depart

\$551: (3) Backward tiration search 3 #852: (3) Forward citation search &

\$553: (48E) substrate and "GaN" and lactive add (layer of

\$554: (12) (US-20020065726-S or US-20046675097-S).did. of #\$555: (483) 883 not igoetz-werner-k.in. camres-michael-d 4856; (476) SSS not SE4

\$557: (415) \$56 and (light adj emitt\$4) \$58: (205) 557 and (concentration with (vars) or chance

#0559: (93) S56 and (n-type with ((compound or composition) #\$ \$60: (65) 559 and (p-type with ((compound or composition \$561: (82) 560 and (electrode or contact)

MSSC: (67) 961 and bittide and thirtness

@ Favorates & Tagged (20)

@ UDC Ø 20eus i. @ Trach

PT r US 6320207 B1 US 621\*\*\* 26611120 hight emitting device having flat growth GaN isver 257/101 Hapar 20010410 Light-emitting gallium mitride-based compound semiconductor device 257/96 US 6204084 USPAT 20010020 Mitride system semiconductor device and method for manufacturing the same 438746 USPAT 20001114 Compound semiconductor device formed of nitrogen-containing gailium 257/76 Compound such as man, signs or ingan Compound semiconductor device formed of nitrogen-containing gallium 19990511 US 5303017 A 257/190 Commound such as SaM, 23648 or inGaM Light-emitting callium nitride-based compound semiconductor device 19990309 US 5880486 A USPAT 257/96 US 5740192 A USPAT 19960414 Speciconductor lavar 372/45 US 6853009 HODET 20050208 Light-emitting semiconductor device using gallium nitride compound 257/94 Semiconductor Mitride semiconductor device US 6839693 USEAT 200501.04 257/14 P . P US 6818465 SEFAT 20041116 Witride semiconductor element and production method for mitride

Nitride semiconductor light-emitting device and optical device and

light-smitting separatus with the nitride semiconductor light-smitting de Boron proophide-based semiconductor device and production method thereof

semiconductor element

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SPAT 20040918

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